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CLAIMS:

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1. A method for determining edge roughness of a feature in a mask, the method comprising:

determining a centerline of the feature based on a representation of the mask;

measuring a first length of a first rib extending from the centerline to one edge of the feature;

measuring a second length of a second rib extending from the centerline to the one edge of the feature; and

comparing the first and second lengths to determine the edge roughness.

- 2. The method of Claim 1, wherein the representation includes a layout of the mask.
- 3. The method of Claim 1, wherein the representation includes a layout of one layer of an integrated circuit.
  - 4. The method of Claim 1, wherein the feature is a line.
  - 5. The method of Claim 1, wherein the feature is a contact.
- 6. A method of repairing a mask, the method comprising: determining an edge roughness of a feature on the mask, wherein if the edge roughness is outside a predetermined value, then using a lithography tool to repair the mask.
- 7. The method of Claim 6, wherein the predetermined value is selected by a user.

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8. The method of Claim 6, wherein determining the edge roughness includes determining a centerline of the feature based on a defect-free representation of the feature.

- 9. The method of Claim 6, wherein the feature includes at least one of a line and a contact.
- 10. A method of repairing a wafer, the method comprising: determining an edge roughness of a feature on the wafer, wherein if the edge roughness is outside a predetermined value, then using a lithography tool to repair the wafer.
- 11. The method of Claim 10, wherein the predetermined value is selected by a user.
- 12. The method of Claim 10, wherein determining the edge roughness includes determining a centerline of the feature based on a defect-free representation of the feature.
- 13. The method of Claim 10, wherein the feature includes at least one of a line and a contact.
- 14. A method of determining corner rounding of a contact in a lithographic mask, the method comprising:

determining a centerline of the contact in a first direction;

providing a plurality of theoretical cuts through the contact in a second direction substantially perpendicular to the first direction, wherein each cut provides a rib extending from the centerline to an edge of the contact; and

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comparing at least two ribs to determine corner rounding, one rib being located near a corner of the contact and another rib not being located near the corner.

15. A method of determining the symmetry of a contact in a lithographic mask, the method comprising:

determining a first centerline of the contact in a first direction;

providing a plurality of theoretical cuts through the contact in a second direction substantially perpendicular to the first direction, wherein each cut provides a first critical dimension extending from a first edge of the contact to a second edge of the contact;

determining a centerline of the contact in the second direction;

providing a plurality of theoretical cuts through the contact in a first direction substantially perpendicular to the first direction, wherein each cut provides a second critical dimension extending from a third edge of the contact to a fourth edge of the contact; and

comparing the first and second critical dimensions to determine the symmetry of the contact.

- 16. A method of repairing a mask, the method comprising: determining any corner rounding of a contact on the wafer, wherein if the edge roughness is outside a predetermined value, then using a lithography tool to repair the wafer.
- 17. The method of Claim 16, wherein the predetermined value is selected by a user.

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18. The method of Claim 16, wherein determining the edge roughness includes determining a centerline of the feature based on a defect-free representation of the feature.

- 19. An integrated circuit comprising:
- a plurality of features for performing a function; and at least one repaired feature, wherein the at least one repaired feature resulted from an automatic defect severity score.
- 20. The integrated circuit of Claim 19, wherein the at least one repaired feature includes a line.
- 21. The integrated circuit of Claim 19, wherein the at least one repaired feature includes a contact.
- 22. The integrated circuit of Claim 19, wherein the at least one repaired feature includes an OPC feature.
- 23. The integrated circuit of Claim 19, wherein the at least one repaired feature includes one of a hammerhead, a serif, and a bias.
- 24. A mask inspection system, the system comprising: means for generating a simulated wafer image of a feature on a mask;

means for determining a centerline for the simulated wafer image based on a defect-free representation of the feature; and means for measuring an aspect of the simulated wafer image based on the centerline.

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25. The system of Claim 24, wherein the aspect includes line edge roughness.

- 26. The system of Claim 25, further including means for evaluating possible repairs made to the mask based on the line edge roughness.
- 27. The system of Claim 26, further including a mask repair tool receiving signals from the means for evaluating possible repairs.
- 28. The system of Claim 25, wherein the aspect includes corner rounding.
- 29. The system of Claim 28, further including means for evaluating possible repairs made to the mask based on the corner rounding.
- 30. The system of Claim 29, further including a mask repair tool receiving signals from the means for evaluating possible repairs.
- 31. An inspection system for analyzing a feature on a mask, the system comprising:

means for generating a simulated wafer image of the feature; means for determining a centerline for the simulated wafer image of the feature based on a defect-free representation of the feature; and

means for determining whether the feature passes a predetermined standard.

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32. The system of Claim 31, wherein the predetermined standard includes line edge roughness of the simulated wafer image.

- 33. The system of Claim 32, further including means for evaluating possible repairs made to the mask based on the line edge roughness.
- 34. The system of Claim 33, further including a mask repair tool receiving signals from the means for evaluating possible repairs.
- 35. The system of Claim 31, wherein the predetermined standard includes symmetry of the simulated wafer image.
- 36. The system of Claim 35, wherein the symmetry indicates corner rounding of the simulated wafer image.
- 37. The system of Claim 36, further including means for evaluating possible repairs made to the mask based on the corner rounding of the simulated wafer image.
- 38. The system of Claim 37, further including a mask repair tool receiving signals from the means for evaluating possible repairs.
- 39. A method of quantifying a quality of a feature on a mask, the method comprising:
  - (a) determining a centerline of the feature;
- (b) measuring a first length of a first rib extending from the centerline to one edge of the feature;

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(c) measuring a second length of a second rib extending from the centerline to the one edge of the feature;

- (d) comparing the first and second lengths;
- (e) continuing steps (b), (c), and (d) for a plurality of times; and
- (f) calculating a score for the quality of the feature based on steps (a) -(e).
  - 40. A physical mask comprising:

at least one feature being modified based on analyzing a centerline of a simulated wafer image of the feature, the centerline determined by a defect-free representation of the feature; and

at least one feature being unmodified based on analyzing the centerline.

- 41. The mask of Claim 40, wherein the defect-free representation of the feature includes a reference mask, the reference mask corresponding to a defect-free physical mask.
- 42. Computer software for determining edge roughness of a feature in a mask, the software comprising:

means for determining a centerline of the feature based on a representation of the mask;

means for measuring a first length of a first rib extending from the centerline to one edge of the feature;

means for measuring a second length of a second rib
extending from the centerline to the one edge of the feature; and
means for comparing the first and second lengths to
determine the edge roughness.

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43. Computer software for determining corner rounding of a contact in a lithographic mask, the software comprising:

means for determining a centerline of the contact in a first direction;

means for providing a plurality of theoretical cuts through the contact in a second direction substantially perpendicular to the first direction, wherein each cut provides a rib extending from the centerline to an edge of the contact; and

means for comparing at least two ribs to determine corner rounding, one rib being located near a corner of the contact and another rib not being located near the corner.

44. Computer software for determining the symmetry of a contact in a lithographic mask, the software comprising:

means for determining a first centerline of the contact in a first direction;

means for providing a plurality of theoretical cuts through the contact in a second direction substantially perpendicular to the first direction, wherein each cut provides a first critical dimension extending from a first edge of the contact to a second edge of the contact;

means for determining a centerline of the contact in the second direction;

means for providing a plurality of theoretical cuts through the contact in a first direction substantially perpendicular to the first direction, wherein each cut provides a second critical dimension extending from a third edge of the contact to a fourth edge of the contact; and

means for comparing the first and second critical dimensions to determine the symmetry of the contact.